<u>TOSHIBA</u>

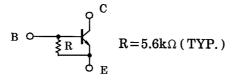
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

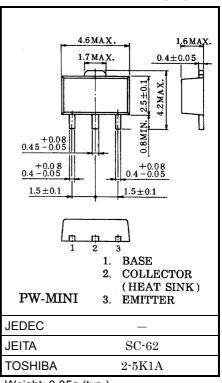
RN5002

Motor Drive Circuit Applications Power Amplifier Applications Power Switching Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Small flat package
- P_C = 1~2W (mounted on ceramic substrate)
- Complementary to RN6002

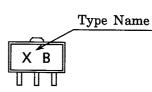
Equivalent Circuit





Weight: 0.05g (typ.)

Marking



Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit	
Collector-base voltage	V _{CBO}	30	V	
Collector-emitter voltage	V _{CEO}	30	V	
Emitter-base voltage	V _{EBO}	5	V	
Collector current	Ι _C	2	А	
Base current	Ι _Β	0.4	А	
Collector power dissipation	PC	500	mW	
Collector power dissipation	P _C *	1000	mW	
Junction temperature	Tj	150	°C	
Storage temperature range	T _{stg}	-55~150	°C	

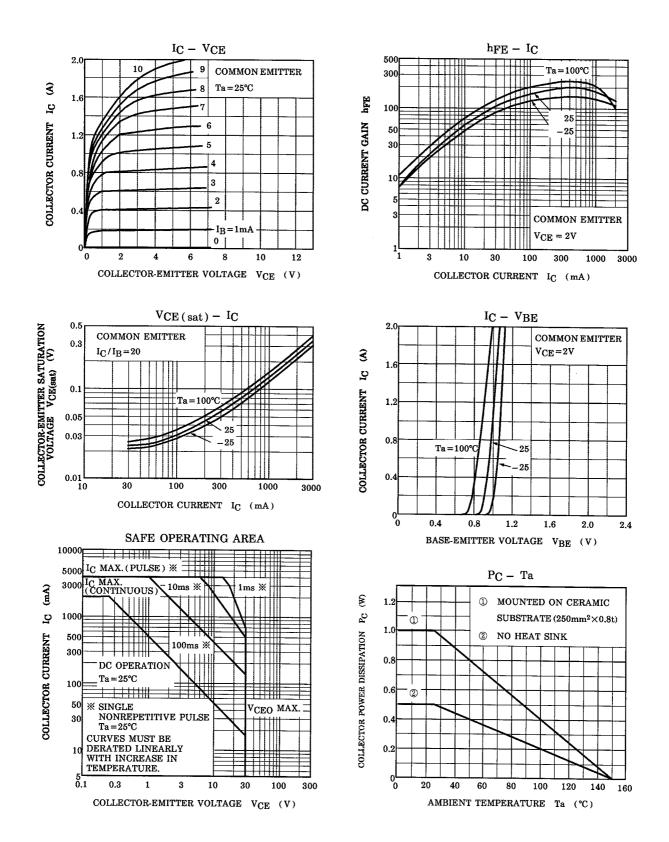
* : Mounterd on ceramic substrate (250mm² × 0.8t)

Unit: mm

Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-offcurrent	I _{CBO}	_	V _{CB} = 30V, I _E = 0	_	_	0.1	μA
Emitter cut-off current	I _{EBO}	_	V _{EB} = 5V, I _C = 0	0.68	0.89	1.28	mA
Collector-emitter breakdown voltage	V _{(BR)CES}	_	I _C = 10mA	30	-	_	V
DC current gain	h _{FE (1)}		V _{CE} = 2V, I _C = 0.5A	100	_	360	_
	h _{FE (2)}		V _{CE} = 2V, IC = 2.0A	50	_	_	
Collector-emitter saturation voltage	V _{CE (sat)}	_	I _C = 1A, I _B = 0.05A	_	_	0.5	V
Base-emitter saturation voltage	V _{BE (sat)}	_	I _C = 1A, I _B = 0.05A	_	_	1.2	V
Transition frequency	f _T	_	V _{CE} = 2V, I _C = 0.5A	_	120	_	MHz
Collector output capacitance	C _{ob}	_	V _{CB} = 10V, I _E = 0, f = 1 MHz	_	40	_	pF
Resistor	R	—	—	3.9	5.6	7.3	kΩ

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